

FORM PTO-1390
REV. 2/01

U. S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTORNEY'S DOCKET NUMBER
05823.0191TRANSMITTAL LETTER TO THE UNITED STATES
DESIGNATED/ELECTED OFFICE (DO/EO/US)
CONCERNING A FILING UNDER 35 U.S.C. 371U.S. APPLICATION NO.
(If filed in PCT)

097762435

INTERNATIONAL APPLICATION NO.

PCT/KR98/00462

INTERNATIONAL FILING DATE

December 24, 1998

PRIORITY DATE CLAIMED

August 14, 1998

TITLE OF INVENTION

AN IMPROVED METHOD FOR MANUFACTURING CRYSTALLINE
LAYERED SODIUM DISILICATE

APPLICANT(S) FOR DO/EO/US

Jung Min LEE; Jeong Kwon SUH; Soon Yong JEONG; Chun Hee PARK;
Jeong Hwan PARK; Jong An KIM

Applicant(s) herewith submits to the United States Designated/Elected Office (DO/EO/US) the following items and other information:

1. ☒ This is a **FIRST** submission of items concerning a filing under 35 U.S.C. 371.
2. ☐ This is a **SECOND** or **SUBSEQUENT** submission of items concerning a filing under 35 U.S.C. 371.
3. ☐ This is an express request to begin national examination procedures (35 U.S.C. 371(f)). The submission must include items (5), (6), (9) and (21) indicated below.
4. ☒ The US has been elected by the expiration of 19 months from the priority date (Article 31).
5. ☒ A copy of the International Application as filed (35 U.S.C. 371 (c)(2)).
 - a. ☒ is attached hereto (required only if not communicated by the International Bureau).
 - b. ☐ has been communicated by the International Bureau.
 - c. ☐ is not required, as the application was filed with the United States Receiving Office (RO/US).
6. ☐ An English language translation of the International Application as filed (35 U.S.C. 371 (c)(2)).
 - a. ☐ is attached hereto.
 - b. ☐ has been previously submitted under 35 U.S.C. 154 (d)(4).
7. ☒ Amendments to the claims of the International Application under PCT Article 19 (35 U.S.C. 371 (c)(3)).
 - a. ☐ are attached hereto (required only if not communicated by the International Bureau).
 - b. ☐ have been communicated by the International Bureau.
 - c. ☐ have not been made; however, the time limit for making such amendments has NOT expired.
 - d. ☒ have not been made and will not be made.
8. ☐ An English language translation of the amendments to the claims under PCT Article 19 (35 U.S.C. 371 (c)(3)).
9. ☐ An oath or declaration of the inventor(s) (35 U.S.C. 371 (c)(4)).
10. ☐ An English language translation of the annexes of the International Preliminary Examination Report under PCT Article 36 (35 U.S.C. 371 (c)(5)).

Items 11 to 20 below concern document(s) or information included:

11. ☐ Information Disclosure Statement under 37 CFR 1.97 and 1.98.
12. ☐ An assignment document for recording. A separate cover sheet in compliance with 37 CFR 3.28 and 3.31 is included.
13. ☐ A FIRST preliminary amendment.
14. ☐ A SECOND or SUBSEQUENT preliminary amendment.
15. ☐ A Substitute specification.
16. ☐ A change of power of attorney and/or address letter.
17. ☐ A computer-readable form of the sequence listing in accordance with PCT Rule 13ter.2 and 35 U.S.C. 1.821-1.825.
18. ☐ A second copy of the published international application under 35 U.S.C. 154 (d)(4).
19. ☐ A second copy of the English language translation of the international application 35 U.S.C. 154 (d)(4).
20. ☒ Other items or information:
 - a. ☒ Copy of cover page of International Publication No. WO00/09444.
 - b. ☐ Copy of Notification of Missing Requirements.
 - c. ☐

U.S. APPLICATION NO. (if known) 37 CFR 1.45)

09/762435

INTERNATIONAL APPLICATION NO.
PCT/KR98/00462ATTORNEY'S DOCKET NUMBER
05823.019121. ☒ The following fees are submitted:**BASIC NATIONAL FEE (37 CFR 1.492 (a) (1) - (5)):**Neither international preliminary examination fee (37 CFR 1.482)
nor international search fee (37 CFR 1.445(a)(2)) paid to USPTO
and International Search Report not prepared by the EPO or JPO

\$1000.00

International preliminary examination fee (37 CFR 1.482) not paid to
USPTO but International Search Report prepared by the EPO or JPO

\$860.00

International preliminary examination fee (37 CFR 1.482) not paid to
USPTO but International Search fee (37 CFR 1.445(a)(2)) paid to USPTO

\$710.00

International preliminary examination fee (37 CFR 1.482) paid to USPTO
but all claims did not satisfy provisions of PCT Article 33(1)-(4)

\$690.00

International preliminary examination fee (37 CFR 1.482) paid to USPTO
and all claims satisfied provisions of PCT Article 33 (1)-(4)

\$100.00

ENTER APPROPRIATE BASIC FEE AMOUNT =

\$1000.00

Surcharge of \$130.00 for furnishing the oath or declaration later than
months from the earliest claimed priority date (37 CFR 1.492 (e)).☐ 20 ☐ 30

\$

| CLAIMS | NUMBER FILED | NUMBER EXTRA | RATE | | |
|---|--------------|--------------|------------|----|--|
| Total Claims | 6 | - 20 = | x \$18.00 | \$ | |
| Independent Claims | 2 | - 3 = | x \$80.00 | \$ | |
| MULTIPLE DEPENDENT CLAIM(S) (if applicable) | | | + \$270.00 | \$ | |

TOTAL OF THE ABOVE CALCULATIONS =

\$1000.00

☒ Applicant claims small entity status. See 37 CFR 1.27. The fees indicated above are reduced by 1/2.

\$500.00

SUBTOTAL =

\$500.00

Processing fee of \$130.00 for furnishing the English translation later than
months from the earliest priority date (37 CFR 1.492(f)).☐ 20 ☐ 30

\$

TOTAL NATIONAL FEE =

500.00

Fee for recording the enclosed assignment (37 CFR 1.21 (h)). The assignment must be accompanied by
an appropriate cover sheet (37 CFR 3.28, 3.31). \$40.00 per property.

\$

TOTAL FEES ENCLOSED =

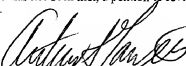
\$500.00

Amount to be refunded: \$

charged: \$

- a. ☒ A check in the amount of \$ 500.00 to cover the above fees is enclosed.
- b. ☐ Please charge my Deposit Account No. _____ in the amount of \$ _____ to cover the above fees.
A duplicate copy of this sheet is enclosed.
- c. ☒ The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment to
Deposit Account No. 06-0916. A duplicate copy of this sheet is enclosed.
- d. ☐ Fees are to be charged to a credit card. **WARNING:** Information on this form may become public. **Credit card information should not be included on this form.** Provide credit card information and authorization on PTO-2038.

NOTE: Where an appropriate time limit under 37 CFR 1.494 or 1.495 has not been met, a petition to revive (37 CFR 1.137 (a) or (b)) must be filed and granted to restore the application to pending status.

SEND ALL CORRESPONDENCE TO:Finnegan, Henderson, Farabow, Garrett & Dunner, L.L.P.
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DATED: February 8, 2001

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09/762435
JG02 Rec'd PCT/PTO 08 FEB 2001

WO 00/09444

PCT/KR98/00462

AN IMPROVED METHOD FOR MANUFACTURING CRYSTALLINE LAYERED SODIUM DISILICATE

BACKGROUND OF THE INVENTION

Field of the Invention

The present invention relates to an improved method for manufacturing a crystalline layered sodium disilicate and more particularly, to the improved method for manufacturing the crystalline layered sodium disilicate comprising the steps including the preparation of granules in a certain ratio of anhydrous sodium silicate cullet, a starting material, in the presence of some binders such as water and aqueous solution of sodium silicate, followed by a crystallization step of the granules, wherein a small amount of final product is recycled to the prior crystallization step in order to prevent the attachment of granules to an inner crystallization device, which occurs due to local sintering in a high-temperature crystallization condition of continual process and also to further enhance the unit productivity during the mass production of crystalline layered sodium disilicate.

Description of the Related Art

The term "cullet" used as a starting material of this invention, which has been frequently used as a raw material in a field involved in the manufacture of sodium silicate solution, refers to a compound in a small lump or piece derived from amorphous sodium silicate, prepared in such a manner that a mixture of silica and sodium carbonate in an appropriate molar ratio (ratio of SiO_2 to Na_2O , namely $\text{SiO}_2/\text{Na}_2\text{O}$) is heated at the temperature of 1000-1400°C, melted and cooled.

In addition, the term "layered sodium silicate" refers to crystalline silica compounds expressed by $(\text{Na}_2\text{O})_y(\text{SiO}_2)_x$ (where y/x varies differently

depending on the crystal structure and has the common values ranging from 2 to 11); among them, the crystalline layered sodium silicate expressed by $\text{Na}_2\text{Si}_2\text{O}_5$ is reported to have various crystal forms such as α , β , γ and δ -phases, and with its excellent adsorptivity and ion-exchange capacity originated from structural specificity, the crystalline layered sodium disilicate has been useful as a catalytic carrier or in a variety of chemical processes such as separation and purification. With its higher binding capacity on the hardness components in water such as Ca^{2+} and Mg^{2+} in particular, the crystalline layered sodium disilicate in δ -phase, the crystalline layered sodium disilicate has been recently used as a water softener or detergent composition builder.

However, the process for manufacturing the crystalline layered sodium disilicate in δ -phase has recognized some disadvantages in that severe foaming induced by a leakage of remaining water is generated in the initial crystallization step, and with sintering and shrinkage of particles, they are deposited in the crystallization device.

To comply with this matter, U.S. Patent No. 5,211,930 has added a method for recycling 10-50wt% of final product to the crystallization step, thus preventing deposit of products in a calcination device.

However, the above method has proven to be uneconomical with poor unit productivity during mass production, since a large amount (10-50wt%) of final product is recycled to the device; the reduction of unit productivity cannot be overcome in a process where powders containing a large amount of water is fed.

Under such circumstances, in an effort to prevent the deposits of final product in the crystallization device, the inventor et al. in their respective patents (U.S. Patent No. 5,567,404, its corresponding Korea Patent No. 139976 and Korea Patent Appln. No. 97-33207) have disclosed some methods for

manufacturing the crystalline layered sodium disilicate in such a manner that water or aqueous solution of sodium silicate in a small amount for agglomeration is added to a cullet powder, a starting material, thereby preparing granules with a small amount of water and then the granules are crystallized in calcination furnace, thus ensuring more simplification of manufacturing process, reduction in energy consumption, and removal of deposits remaining in the device. Notwithstanding this, these methods have still failed to eliminate the deposits of some granules in the device during the crystallization step, when a continual process for mass production is operated.

SUMMARY OF THE INVENTION

To overcome the aforementioned shortcoming that reactants are deposited in a crystallization device, the inventor et al. have found that a process recycling a small amount of final product to the device may not only eliminate the deposit of product in a calcination furnace associated with local sintering occurring at a higher temperature during continual process, but also recycle less amount than that of the U.S. Patent No. 5,211,930, thus resulting in significant increase of unit productivity during mass production. In consequence, the inventor et al. have completed this invention.

Therefore, an object of this invention is to provide an improved method for manufacturing a crystalline layered sodium disilicate, being characterized in that some defects found in the crystallization device have been completely removed by specifying the agglomeration and recycling steps for possible continual process, thereby improving unit productivity during mass production.

Detailed Description of the Invention

This invention is characterized by an improved method for

manufacturing crystalline layered sodium disilicate comprising the subsequent steps of a) preparing granules with the addition of water as binder to anhydrous sodium silicate cullet powder; b) drying and crystallizing the granules by heat calcination to prepare sodium disilicate, wherein 3-5wt% of
5 final product, sodium disilicate, is recycled to the prior crystallization step.

Also, this invention is characterized by an improved method for manufacturing the crystalline layered sodium disilicate comprising the subsequent steps of a) preparing granules with the addition of an aqueous solution of sodium silicate as binder to anhydrous sodium silicate cullet
10 powder; b) drying and crystallizing the granules by heat calcination to prepare sodium disilicate, wherein 3-5wt% of final product, sodium disilicate, is recycled to the prior crystallization step.

This invention is explained in detail as follows:

This invention relates to a method for manufacturing a crystalline
15 layered sodium disilicate, performed in such subsequent steps that a certain amount of water or aqueous solution of sodium silicate is added to an anhydrous sodium silicate cullet powder comprising a certain ratio of chemical composition for the preparation of granules, followed by drying and calcining for their crystallization, wherein a step of recycling some final
20 products to the crystallization device has contributed much to settlement of several problems associated with the continual operation, since the recycling process makes it possible to separate the reactants, which may be sintered in the device at a high temperature (500-800°C), from inner wall of the crystallization device. According to this invention, the recycling step of final
25 product in small amounts is available in that from the step of preparing granules, the round-form agglomeration may minimize the contact area in the crystallization device.

As described in the respective patents (U.S. Patent No. 5,567,404, its

corresponding Korea Patent No. 139976 and Korea Patent Appln. No. 97-33207) disclosed by the inventor et al., the agglomeration step highlighted by this invention, which has several advantages in that a) unlike the conventional method with crystallization process for powder material, high-density materials supplied to crystallization device may cause no dust with a higher unit productivity; b) minimization of contact area with the device due to agglomeration may significantly prevent any attachment caused by the sintering of reactants. However, the manufacturing method using the agglomeration step has failed to efficiently prevent the attachment of reactants to the inner wall of calcination device during mass production of continual operation.

To efficiently prevent the attachment of granules to the device, a small amount of final product (less than 5wt%) is recycled to separate the reactants sintered from inner wall of the crystallization device.

The process for manufacturing a crystalline layered sodium disilicate of this invention is briefly illustrated in Fig. 1 and each process step is explained in more detail as follows:

First, a cullet (the molar ratio of SiO_2 to Na_2O is 1.80-2.20) is pulverized to make a cullet powder having less than 0.8 mm ($D_{50} \approx 0.3$ mm) in its particle size;

Second, water and aqueous solution of sodium silicate (the molar ratio of SiO_2 to Na_2O used as a binder is 2.0-3.3, solid content: 15-40wt%) is added to the cullet powder to prepare a granule having 1-30mm (volumetric density: 1.1-1.6g/cm³) in its diameter; hence, the water used for the agglomeration of cullet powder acts not only as a binder, but also as an indispensable component for the phase transfer due to hydration. In view of the fact that the manufacturing conditions for granules vary differently depending upon the amount of water, water may be directly used but the use of aqueous solution

of sodium silicate may enhance the adhesive power of solid component in the binder composition of cullet powder, thus making it easier to adjust the amount of water.

It is preferred that 5-30wt% of water is added to an anhydrous sodium silicate cullet powder, when water is directly used as a binder. Further, it is preferred that an aqueous solution of sodium silicate containing 15-40wt% of solid component is used as a binder for the adjustment of water contents; the amount of sodium silicate in aqueous solution is in the range of 10-30wt% to the anhydrous sodium silicate cullet powder.

Hence, the agglomeration device includes any type of agglomeration device such as a round type, a cylindrical type, fluidized type and molding press.

Then, the step of drying the granules is performed, followed by calcination to finally prepare the crystalline layered sodium disilicate.

According to this invention, granules are subjected to a drying step before it is delivered to a continual calcination device, since such drying step may effectively prevent the combining of granules induced by the adhesiveness of aqueous solution of sodium silicate present in the surface of granules, while making it easier not only to deliver the granules, but also to form the phase variation during crystallization by facilitating the hydration in the granules.

However, the drying step at extremely high temperature is responsible for generation of any impurities, thus reducing the purity of final product. In this respect, it is preferred that the drying step is performed at 80-200°C until the amount of evaporated water becomes 0.2-1.0wt%. The volumetric density of the granules, so dried, should be maintained at 1.1-1.6g/cm³.

The granules are placed at a rotary calcination furnace, crystallized for 0.1-1 hour at 650-800°C to form a material with 0.1-0.5g/cm³ of volumetric

density, and pulverized with a crusher.

Meantime, the recycling step highlighted by this invention is to re-supply some of final product to a crystallization device, together with dried granules. Hence, the particle size of final product for recycling is of little significance but the step of recycling some micropowders may cause the occurrence of dusts, which will result in heavy load to a bag filter during continual operation. Therefore, it is preferred that the particle size of final product for recycling is in the range of 0.2-1.0mm ($D_{50} \approx 0.6 \mu\text{m}$).

The recycling step using a larger amount of final product is advantageous in preventing any attachment or formation of mass in the device but this may adversely affect the unit productivity. To achieve the objective of this invention, therefore, a priority should be given to the limitedness of the recycling amount of final product. Therefore, the recycling amount of final product is less than 5 wt% at maximum in proportion to the total amount of granule, preferably 3-5 wt%. Hence, if the recycling amount is less than 3 wt%, a sintering occurs in some granules which are momentarily attached to or detached from the inner wall of a calcination furnace, or a mass of granules is formed or sintered. At this time, the α -type crystal phase occurs partially in the final product.

Further, if the recycling amount of final product exceeds 5 wt%, the individual rotation of granules impedes their swift delivery, when contacted with an excessive recycling amount of final product during the crystallization. Under such circumstances, any retention time of granules cannot be constantly maintained in addition to possible occurrence of dusts and furthermore, the unit productivity becomes significantly reduced thereto.

As such, the product prepared by recycling an appropriate amount of final product exhibits an excellent physical property as a δ -phase crystalline layered sodium disilicate in high purity.

The salient points relating to the process for manufacturing a crystalline layered sodium disilicate of this invention may be summarized as follows:

First, the homogeneous crystallization of granules may be ensured by recycling a small amount of final product together with granules, and the coagulation of granules and the inner wall of the device due to local sintering during crystallization may be prevented by the recycling powder.

Second, since the attachment of granules in the device may be prevented, the continual process is available and by recycling a small amount of final product, a higher unit productivity may also lead to an optimization of the process thereto.

This invention is explained in more detailed based on the following examples but is not limited by these examples.

Example 1

5kg of a cullet powder (molar ratio of $\text{SiO}_2/\text{Na}_2\text{O}$: 2.03, particle size: $D_{50} \approx 0.3$ mm) was placed at a hopper for raw material, and transferred to a round-type agglomeration device at a speed of 60g/min ($\phi 40$ cm, Yongjin Machinery Co. of Korea). While rotating the material at 15 rpm with an angle of inclination at 48° , aqueous solution of silicate sodium having the molar ratio of 2.26 in $\text{SiO}_2/\text{Na}_2\text{O}$ (solid content: 30 wt%, Shinhoong Silicate Product of Korea) was added dropwise at 13g/min to give granules. Then, the granules in round form having about 8 mm in its average diameter were continuously obtained.

The granules dried by a air flow oven at 120°C for 30 mins (amount of evaporated water: 0.5 wt%, volumetric density: 1.31 g/cm³), were placed at a hopper for raw material in a rotary calcination furnace ($\phi 20$ cm \times ℓ 300 cm, Dong-A Heavy Industries of Korea), and transferred to a calcination furnace

(feeding rate by a vibration feeding device: 200g/min) at 725 °C, together with the amount, indicated in Table 1, of final pulverized product for recycling at a speed of 6g/min. Hence, the reactant was crystallized at the retention time of 20 mins with the angle of inclination at 0.5 ° and at 8 rpm.

During such crystallization, any attachment of reactant to the inner device was not observed. Then, a whitish porous crystalline layered sodium disilicate with the expanded volumetric density of about 0.26g/cm³ was obtained, while keeping the initial granule form via appropriate rotational operation of individual granules.

Example 2

The granules prepared in the same manner as Example 1 was transferred to a calcination furnace at a speed of 200 g/min, together with the amount, indicated in Table 1, of final pulverized product for recycling at a speed of 10g/min. Then, a crystalline layered sodium disilicate was prepared in the same manner as Example 1. During such process, any attachment of reactant to the inner device was not observed.

Comparative example 1

The granules prepared in the same manner as Example 1 were transferred to a calcination furnace at a speed of 200 g/min, while any final product for recycling was not added. Then, a crystalline layered sodium disilicate was prepared in the same manner as Example 1. During the manufacturing process, some reactants was momentarily sintered and attached to an inner wall of calcination device. The formation of mass or attachment among some granules were observed.

Comparative example 2

The granules prepared in the same manner as Example 1 were transferred to a calcination furnace at a speed of 200 g/min, together with the amount, indicated in Table 1, of final pulverized product for recycling at a speed of 20g/min. Then, a crystalline layered sodium disilicate was prepared in the same manner as Example 1. Dusts were generated in the process of supplying the raw materials and individual rotation of granules were insufficiently made due to recycling of final product in excess amount.

Experimental example 1: Attachment of granules in the calcination device

The attachment of granules in the calcination device was observed with naked eye at the tube end of crystallization device. The results were shown in the following Table 1.

Experimental example 2: Measurement for the binding capacity of final product to hardness component

The final products prepared from Examples 1-2 and Comparative example 1-2 was pulverized by ball-mill for 30 minutes and classified to make the particle size of 43-104 μm . Then, the binding capacity to Ca^{2+} and Mg^{2+} was measured in the following manner.

(1) Measurement for the binding capacity to Ca^{2+}

About 1.0g of sample was weighed, transferred to a stirrer at 25°C and then, 1000 ml of hard water (aqueous solution of Ca^{2+} , hardness: 200mg Ca^{2+} /l) was added to the sample. The mixture was stirred for 15 minutes and filtered off immediately. 25ml of the remaining solution, accurately collected, was transferred to a 100ml Erlenmeyer flask, followed by the addition of 2-3 ml of $\text{NH}_4\text{-NH}_4\text{Cl}$ buffer solution (pH 10). E.B.T indicator was added to the mixture, and titrated with a standard solution of 0.01M EDTA. Then, the

binding capacity to Ca^{2+} was calculated using the following equation 1.

Equation 1.

$$\text{Binding capacity to } \text{Ca}^{2+} (\text{mgCa}^{2+}/\text{g}) = [12.5 - (t \times f)/w] \times (200/12.5)$$

Where, t is a consumption amount of EDTA (ml); w is a weight of sample(g); and f is a factor of EDTA solution used.

(2) Measurement for the binding capacity to Mg^{2+}

About 1.0g of sample was weighed, transferred to a stirrer at 25°C and then, 1000 ml of hard water (Mg^{2+} solution, hardness: 120 mgCa^{2+}/ℓ) was added to the sample. The mixture was stirred for 15 minutes and filtered off immediately. 25ml of the remaining solution, accurately collected, was transferred to a 100ml Erlenmeyer flask, followed by the addition of potassium cyanide solution (10%) 0.5 ml, several drops of hydroxychloride ammonium solution (10%) and 2-3 ml of $\text{NH}_4\text{-NH}_4\text{Cl}$ buffer solution (pH 10). E.B.T indicator was added to the mixture, and titrated with a standard solution of 0.01M EDTA. Then, the binding capacity to Mg^{2+} was calculated using the following equation 2.

Equation 2.

$$\text{Binding capacity to } \text{Mg}^{2+} (\text{mgMg}^{2+}/\text{g}) = [12.5 - (t \times f)/w] \times (120/12.5)$$

Where, t is a consumption amount of EDTA (ml); w is a weight of sample(g); and f is a factor of EDTA solution used.

Table. 1

| Category | Product for recycling | | Attachment in calcination device | Binding capacity in terms of hardness | |
|-------------------|------------------------------|---|--|--|--|
| | Recycling amount (wt%) | Average particle size(D50, μ m) | | Ca ²⁺ (mg Ca ²⁺ /g) | Mg ²⁺ (mg Mg ²⁺ /g) |
| Examp. 1 | 3 | 0.6 | Not attached | 109.7 | 91.2 |
| Examp. 2 | 5 | 0.6 | Not attached | 112.5 | 92.4 |
| Comp. examp. 1 | 0 | - | Attached partially or mass-formed | 97.3 | 76.7 |
| Comp. examp. 2 | 10 | 0.6 | Not attached but unavailable in swift rotation | 107.3 | 89.2 |

As mentioned above, this invention relates to a method for manufacturing the crystalline layered sodium disilicate comprising the steps including the preparation of granules from an anhydrous sodium silicate cullet with the addition of some binders such as water and aqueous solution of sodium silicate, followed by a crystallization process of the granules, thus ensuring that a small amount of final product is recycled to the prior crystallization step in order to prevent the attachment of granules to an inner crystallization device, which occurs due to local sintering in a high-temperature crystallization condition of continual process and also to further enhance the unit productivity during the mass production of crystalline

layered sodium disilicate. Further, the crystalline layered sodium disilicate prepared by this invention has an excellent physical property, when the granules are crystallized.

CLAIMS

What is claimed is:

1. A process for manufacturing crystalline layered sodium disilicate comprising the steps of a) preparing granules with the addition of water as binder to anhydrous sodium silicate cullet powder; and b) drying and crystallizing the granules by calcination to prepare sodium disilicate, wherein 3-5wt% of final product, sodium disilicate, is recycled to the prior crystallization step.
- 10 2. The process for manufacturing crystalline layered sodium disilicate according to claim 1, wherein the water as said binder component is added to the anhydrous sodium silicate cullet powder in the range of 5-30 wt%.
- 15 3. The process for manufacturing crystalline layered sodium disilicate according to claim 1, wherein the crystallization step is performed at 650-800°C.
4. A process for manufacturing crystalline layered sodium disilicate comprising the steps of a) preparing granules with the addition of an aqueous
20 solution of sodium silicate as binder to anhydrous sodium silicate cullet powder; and b) drying and crystallizing the granules by calcination to prepare sodium disilicate, wherein 3-5wt% of final product, sodium disilicate, is recycled to the prior crystallization step.
- 25 5. The process for manufacturing crystalline layered sodium disilicate according to claim 4, wherein an aqueous solution of sodium silicate as said binder component (molar ratio of $\text{SiO}_2/\text{Na}_2\text{O}$: 2.0-3.3, solid content: 15-40 wt%) is added to the anhydrous sodium silicate cullet powder in the range of 10-30

wt%

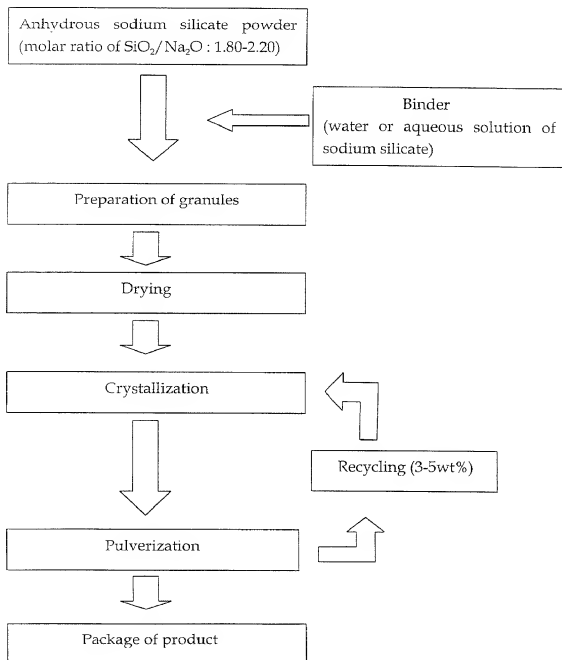
6. The process for manufacturing crystalline layered sodium disilicate according to claim 4, wherein the crystallization step is performed at 650-800°C.

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FIGURE

FIG. 1



DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare that: my residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first, and sole inventor (if only one name is listed below) or an original, first, and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

AN IMPROVED METHOD FOR MANUFACTURING CRYSTALLINE LAYERED SODIUM DISILICATE

the specification of which:

is attached hereto; or

was filed as United States Application Serial No.

on _____, and was amended on _____

(if applicable) or

was filed as PCT International Application Number PCT/KR98/00462

on December 24, 1998, and was amended on _____

(if applicable)

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR § 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. § 119(a)-(d) or § 365(b) of any foreign application(s) for patent or inventor's certificate or § 365(a) of any PCT International application(s) designating at least one country other than the United States, listed below and have also identified below, any foreign application(s) for patent or inventor's certificate, or any PCT International application(s) having a filing date before that of the application(s) of which priority is claimed:

| Country | Application Number | Date of Filing | Priority Claimed Under 35 U.S.C. 119 | |
|---------|--------------------|----------------|--------------------------------------|-----------------------------|
| KR | 98-32993 | 14 August 1998 | <input type="checkbox"/> YES | <input type="checkbox"/> NO |
| | | | <input type="checkbox"/> YES | <input type="checkbox"/> NO |

I hereby claim the benefit under 35 U.S.C. § 119(c) of any United States provisional application(s) listed below:

| Application Number | Date of Filing |
|--------------------|----------------|
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I hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s) or § 365(c) of any PCT International application(s) designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application(s) in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR § 1.56 which became available between the filing date of the prior application(s) and the national or PCT International filing date of this application:

| Application Number | Date of Filing | Status (Patented, Pending, Abandoned) |
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I hereby appoint the following attorney and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith. **FINNEGAN, HENDERSON, FARABOW, GARRETT & DUNNER, L.L.P.**, Douglas B. Henderson, Reg. No. 20,291; Bord F. Farabow, Jr., Reg. No. 20,630; Arthur S. Garrett, Reg. No. 20,338; Donald R. Dunner, Reg. No. 19,073; Brian G. Brunsfold, Reg. No. 22,593; Tipton D. Jennings, IV, Reg. No. 28,645; Jerry D. Voight, Reg. No. 23,020; Laurence R. Heffer, Reg. No. 20,827; Kenneth E. Payne, Reg. No. 23,098; Herbert H. Mintz, Reg. No. 26,691; C. Larry O'Rourke, Reg. No. 26,014; Albert J. Santorelli, Reg. No. 22,610; Michael C. Elmer, Reg. No. 25,857; Richard H. Smith, Reg. No. 20,609; Stephen L. Peterson, Reg. No. 26,325; John M. Romary, Reg. No. 26,331; Bruce C. Zotter, Reg. No. 27,680; Dennis P. O'Reilly, Reg. No. 27,932; Allen M. Sokal, Reg. No. 26,695; Robert D. Bajefsky, Reg. No. 25,387; Richard L. Stroup, Reg. No. 28,487; David W. Hill, Reg. No. 28,220; Thomas L. Irving, Reg. No. 28,619; Charles E. Lipsey, Reg. No. 28,165; Thomas W. Winland, Reg. No. 27,605; Basil J. Lewis, Reg. No. 28,818; Martin I. Fuchs, Reg. No. 28,508; E. Robert Yoches, Reg. No. 30,120; Barry W. Graham, Reg. No. 29,924; Susan Habeman Griffen, Reg. No. 30,907; Richard B. Racine, Reg. No. 30,415; Thomas H. Jenkins, Reg. No. 30,857; Robert E. Converse, Jr., Reg. No. 27,432; Clair X. Mullen, Jr., Reg. No. 20,348; Christopher P. Foley, Reg. No. 31,354; John C. Paul, Reg. No. 30,413; Roger D. Taylor, Reg. No. 28,992; David M. Kelly, Reg. No. 30,953; Kenneth J. Meyers, Reg. No. 25,146; Carol P. Einaudi, Reg. No. 32,220; Walter Y. Boyd, Jr., Reg. No. 31,738; Steven M. Anzalone, Reg. No. 32,095; Jean B. Fordis, Reg. No. 32,984; Barbara C. McCurdy, Reg. No. 32,120; James K. Hammond, Reg. No. 31,964; Richard V. Burgujian, Reg. No. 31,744; I. Michael Jakes, Reg. No. 32,824; Dirk D. Thomas, Reg. No. 32,600; Thomas W. Banks, Reg. No. 32,719; Christopher P. Isaac, Reg. No. 32,616; Bryan C. Diner, Reg. No. 32,409; M. Paul Barker, Reg. No. 32,013; Andrew Chanho Sonu, Reg. No. 33,457; David S. Forman, Reg. No. 33,694; Vincent P. Kovalick, Reg. No. 32,867; James W. Edmonson, Reg. No. 33,871; Michael R. McGurk, Reg. No. 32,045; Joann M. Neth, Reg. No. 36,363; Gerson S. Panitch, Reg. No. 33,751; Cheri M. Taylor, Reg. No. 33,216; Charles E. Van Horn, Reg. No. 40,266; and Linda A. Wadler, Reg. No. 33,218; and _____

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

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